AMENDMENTS TO THE CLAIMS

- 1. (Currently Amended) A power semiconductor module comprising a plurality of semiconductor components situated on substrate regions, wherein
 - each substrate region has a top surface and side faces, wherein side faces of two
 adjacent substrate regions face each other;
 - between each two adjacent substrate regions a <u>an elastic</u> connecting element is arranged such that the connecting element directly contacts the side faces of the two adjacent substrates, wherein said connecting elements are designed to prevent a deformation of one substrate region to continue to an adjacent substrate region; and
 - wherein the connecting elements are formed by recesses in a module housing enclosing said substrate regions, each recess extending from an exterior of the housing.
- 2. (Cancelled)
- 3. (Currently Amended) The power semiconductor module as claimed in claim 2 1, wherein
 - the material recesses are slotted.
- 4. (Previously Presented) The power semiconductor module as claimed in claim 1, wherein
 - the substrate regions are ceramic.
- 5. (Currently Amended) The power semiconductor module as claimed in claim 21, wherein
 - the substrate regions are ceramic.
- 6. (Canceled)

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- 7. (Canceled)
- 8. (Currently Amended) The power semiconductor module as claimed in claim 2_1, wherein
 - the module housing, at least in the regions of the substrate regions, is such that it acts on the substrate regions with a spring force.
- 9. (Previously Presented) The power semiconductor module as claimed in claim 3, wherein
 - the module housing, at least in the regions of the substrate regions, is such that it acts on the substrate regions with a spring force.
- 10. (Canceled)
- 11. (Original) The power semiconductor module as claimed in claim 5, wherein
 - the housing, at least in the regions of the substrate regions, is such that it acts on the substrate regions with a spring force.
- 12. (Canceled)
- 13. (Previously Presented) The power semiconductor module as claimed in claim 1, wherein
 - the power semiconductor module has a housing, which, in an area between the substrate regions, has action points for a mechanical pressure application of the connecting elements, and
 - the housing applies pressure to the individual substrate regions.

- 14. (Currently Amended) A power semiconductor module comprising
 - a plurality of substrate elements having top and bottom surface and side walls, each substrate element comprising a semiconductor component arranged on the top surface of a substrate element;
 - one or a plurality of <u>elastic</u> connecting elements directly contacting opposing side
 walls of two adjacent substrate elements, wherein said connecting elements are
 designed to prevent a deformation of one substrate region to continue to an adjacent
 substrate region;
 - a module housing enclosing said plurality of substrate elements; and
 - wherein the connecting elements are formed by recesses in the module housing extending from an exterior of the housing.
- 15. (Cancelled)
- 16. (Cancelled)
- 17. (Currently Amended) The power semiconductor module as claimed in claim 46 14, wherein
 - the material recesses are slotted.
- 18. (Previously Presented) The power semiconductor module as claimed in claim 14, wherein
 - the substrate is a ceramic.

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- 19. (Currently Amended) The power semiconductor module as claimed in claim 45 14, wherein
 - the module housing, at least in the regions of the substrate elements, is such that it acts on the substrate elements with a spring force.
- 20. (Currently Amended) The power semiconductor module as claimed in claim 14, further comprising
 - a heat sink having a flat surface, wherein a bottom surface of the plurality of substrate elements and said plurality of connecting regions elements are arranged on said flat surface.
- 21. (Currently Amended) The power semiconductor module as claimed in claim 45 14, wherein
 - the module housing in a region between the substrate elements comprises action points for a mechanical pressure application of the connecting elements, and
 - the housing applies pressure to the individual substrate elements.
- 22. (Previously Presented) The power semiconductor module as claimed in claim 1, further comprising
 - a heat sink having a flat surface, wherein the bottom surface of the plurality of substrate elements and said plurality of connecting elements are arranged on said flat surface.
- 23. (Currently Amended) A power semiconductor module comprising:
 - a heat sink having a flat surface,

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- a plurality of substrates arranged on the flat surface of the heat sink;
- a plurality of semiconductor components arranged on the substrates,
- one or a plurality of <u>elastic</u> connecting regions in direct contact with adjacent ones of the substrates and arranged directly on the flat surface of the heat sink between adjacent ones of the substrates, wherein <u>the connecting regions are designed to</u> <u>prevent a deformation of one substrate to continue to an adjacent substrate and</u> the connecting regions are formed by recesses in a module housing enclosing said substrate regions, each recess extending from an exterior of the housing.
- 24 (Previously Presented). A power semiconductor module, comprising:
 - a substrate segmented into a plurality of spaced apart substrate regions;
 - at least one semiconductor component arranged on one or more of the substrate regions;
 - a connecting region arranged in the space between adjacent ones of the substrate regions; and
 - wherein the connecting region forms an articulated hinge with each of the adjacent substrate regions so that the adjacent substrate regions can move relative to one another about the articulated hinges.